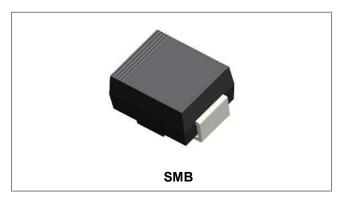






## **SK320B SCHOTTKY RECTIFIER**



### **Features**

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term
- reliability
- Terminals finish: 100% Pure Tin
- Green products in compliance the ROHS directive
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	I <sub>F</sub> (AV)	50% duty cycle @T <sub>C</sub> =100°C, rectangular wave form	3	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	80	Α

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 3A, Pulse, T <sub>J</sub> = 25 °C	0.82	0.90	V
	V <sub>F2</sub>	@ 3A, Pulse, T <sub>J</sub> = 125 °C	0.70	0.75	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R,</sub> T <sub>J</sub> = 25 °C	0.0004	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R,</sub> T <sub>J</sub> = 125 °C	0.03	6.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C, f_{SIG} = 1MHz$	50	100	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%



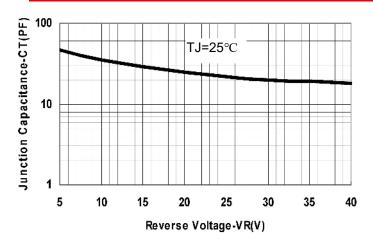




### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	8	°C/W
Approximate Weight	wt	-	0.09	g

## **Ratings and Characteristics Curves**



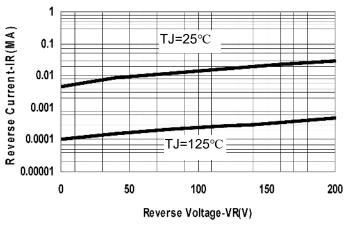


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

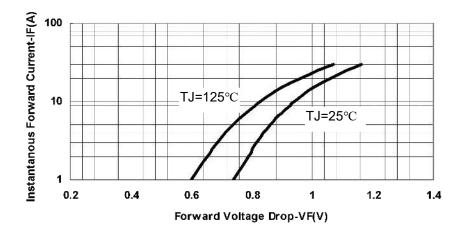


Fig.3-Typical Instantaneous Forward Voltage Characteristics

<sup>•</sup> China - Germany - Korea - Singapore - United States •

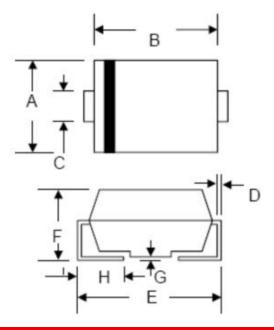
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •







### **Mechanical Dimensions SMB**



CVMDOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.80	2.20	0.071	0.087	
D	0.152	0.305	0.006	0.012	
Е	4.80	5.59	0.189	0.220	
F	2.10	2.60	0.083	0.102	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.52	0.030	0.060	

## **Ordering Information**

Device	Package	Shipping	
SK320B	SMB (Pb-Free)	3000pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

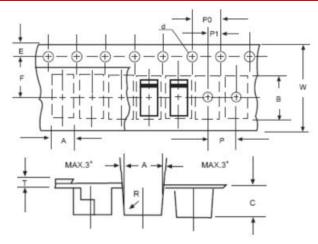
## **Marking Diagram**

SK320B XXXXX Where XXXXX is YYWWL

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Carrier Tape Specification SMB**



SYMBOL	Millimeters		
	Min.	Max.	
Α	3.99	4.19	
В	5.72	5.92	
С	3.23	3.43	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	7.90	8.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	-	0.60	
W	11.80	12.20	

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







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